TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74VCXR162245FT

# LOW-VOLTAGE 16-BIT BUS TRANSCEIVER WITH 3.6V TOLERANT INPUTS AND OUTPUTS

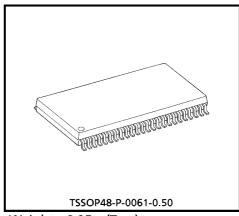
The TC74VCXR162245FT is a high performance CMOS 16-bit BUS TRANSCEIVER. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6V.

This 16bit bus transceiver is controlled by direction control (DIR) inputs and output enable (OE) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The OE inputs can be used to disable the device so that the busses are effectively isolated.

The 26- $\Omega$  series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25g (Typ.)

#### **FEATURES**

- 26- $\Omega$  Series Resistors on all Outputs.
- Low Voltage Operation :  $V_{CC} = 1.8 \sim 3.6 \text{V}$
- High Speed Operation :  $t_{pd} = 3.4$ ns (max.) at  $V_{CC} = 3.0 \sim 3.6$ V
  - :  $t_{pd} = 4.3$ ns (max.) at  $V_{CC} = 2.3 \sim 2.7$ V
  - :  $tpd = 5.7ns (max.) at V_{CC} = 1.8V$
- 3.6V Tolerant inputs and outputs.
- **Output Current** :  $I_{OH}/I_{OL} = \pm 12mA$  (min.) at  $V_{CC} = 3.0V$ 
  - :  $I_{OH}/I_{OL} = \pm 8mA$  (min.) at  $V_{CC} = 2.3V$
  - :  $I_{OH}/I_{OL} = \pm 4mA$  (min.) at  $V_{CC} = 1.8V$
- : ±300mA Latch-up Performance
- ESD Performance : Human Body Model > ±2000V
  - : Machine Model > ±200V
- : TSSOP (Thin Shrink Small Outline Package) Package
- Bidirectional interface between 2.5V and 3.3V signals.
- Power Down Protection is provided on all inputs and outputs
- Supports live insertion/withdrawal (Note 3)
- Note 1) Do not apply a signal to any bus terminal when it is in the output mode. Damage may
  - 2) All floating (high impedance) bus terminal must have their input level fixed by means of pull up or pull down resistors.
  - 3) To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

#### **PIN CONNECTION**

1DIR	10	48	1 <u>O</u> E
1B1	2	47	1A1
1B2	3	46	1A2
GND	4	45	GND
1B3	5	44	1A3
1B4	6	43	1A4
Vcc	7	42	$V_{CC}$
1B5	8	41	1A5
IB6	9	40	1A6
GND	10	39	GND
1B7	11	38.	1A7
1B8	12	37	1A8
2B1	13	36	2A1
2B2	14	35	2A2
GND	15	34	GND
2B3	16	33	2A3
2B4	17	32	2A4
Vcc	18	31	VCC
2B5	19	30	2A5
2B6	20	29	2A6
GND	21	28	GND
2B7	22	27	2A7
2B8	23	26	2A8
2DIR	24	25	20E
	(TOP	VIEW)	

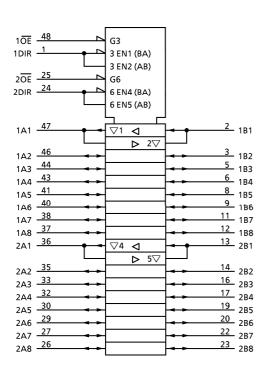
#### TRUTH TABLE

INF	TU	FUNC	TION		
1 <del>OE</del>	1DIR	BUS 1A1-1A8	BUS 1B1-1B8	OUTPUT	
L	L	OUTPUT	INPUT	A = B	
L	Н	INPUT	OUTPUT	B = A	
Н	Х	High Im	pedance	Z	

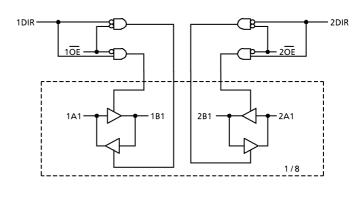
INP	INPUT   FUNCTION   O		TION		
2 <del>OE</del>			603   603   -		
L	L	OUTPUT	INPUT	A = B	
L	Н	INPUT	OUTPUT	B = A	
Н	Х	High Im	Z		

X : Don't CareZ : High impedance

#### **IEC LOGIC SYMBOL**



#### SYSTEM DIAGRAM



980508EBA2'

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#### **MAXIMUM RATINGS**

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	Vcc	-0.5~4.6	V
DC Input Voltage (DIR, OE)	VIN	-0.5~4.6	V
DC Bus I / O Voltage	V/	-0.5~4.6 (Note 1)	v
DC Bus I/O Voltage	V <sub>I</sub> /O	-0.5~V <sub>CC</sub> +0.5 (Note 2)	_
Input Diode Current	Ιικ	<b>–</b> 50	mΑ
Output Diode Current	<sup>I</sup> ок	± 50 (Note 3)	mΑ
DC Output Current	lout	± 50	mΑ
Power Dissipation	PD	400	mW
DC V <sub>CC</sub> / Ground Current Per Supply Pin	I <sub>CC</sub> /I <sub>GND</sub>	± 100	mΑ
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

(Note 1) Off-State

(Note 2) High or Low State. IOUT absolute maximum rating must be observed.

(Note 3) V<sub>OUT</sub><GND, V<sub>OUT</sub>>V<sub>CC</sub>

#### RECOMMENDED OPERATING RANGE

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	\/	1.8~3.6	V
Supply Voltage	VCC	1.2~3.6 (Note 4)	<b>'</b>
Input Voltage (DIR, OE)	VIN	-0.3~3.6	V
Bus I/O Voltage	VI. ( a	0~3.6 (Note 5)	V
Bus 170 Voltage	V <sub>I</sub> /O	0∼ V <sub>CC</sub> (Note 6)	V
		± 12 (Note 7)	
Output Current	IOH/IOL	±8 (Note 8)	mA
		±4 (Note 9)	
Operating Temperature	T <sub>opr</sub>	<b>- 40∼85</b>	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 10)	ns / V

(Note 4) Data Retention Only

(Note 5) Off-State

(Note 6) High or Low State

(Note 7)  $V_{CC} = 3.0 \sim 3.6V$ (Note 8)  $V_{CC} = 2.3 \sim 2.7V$ (Note 9)  $V_{CC} = 1.8V$ 

(Note 10)  $V_{IN} = 0.8 \sim 2.0 \text{V}$ ,  $V_{CC} = 3.0 \text{V}$ 

# **ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta =  $-40 \sim 85^{\circ}$ C, 2.7V < V<sub>CC</sub>  $\leq$  3.6V)

PARAI	METER	SYMBOL	TEST	CONDITION	V <sub>CC</sub> (V)	MIN.	MAX.	UNIT		
Input	"H" Level	VIH			2.7~3.6	2.0	_	V		
Voltage	"L" Level	V <sub>IL</sub>			2.7~3.6	_	0.8	·		
		,,	I <sub>OH</sub> = -100μA	2.7~3.6	V <sub>CC</sub> - 0.2	_				
	"H" Level	۷он	VIN =	$I_{OH} = -6mA$	2.7	2.2	_			
044			V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -8mA	3.0	2.4	_			
Output				I <sub>OH</sub> = - 12mA	3.0	2.2	_	V		
Voltage			V <sub>OL</sub> V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>			I <sub>OL</sub> = 100μA	2.7~3.6	_	0.2	
	"L" Level	$v_{OL}$		I <sub>OL</sub> = 6mA	2.7	_	0.4			
	L Level			I <sub>OL</sub> = 8mA	3.0	_	0.55			
				I <sub>OL</sub> = 12mA	3.0	_	0.8			
Input Leaka	ge Current	IN	$V_{IN} = 0 \sim 3.6$	SV .	2.7~3.6	_	± 5.0	$\mu$ A		
3-State Out Off-State Cu		loz	V <sub>IN</sub> = V <sub>IH</sub> o V <sub>OUT</sub> = 0~3		2.7~3.6	1	± 10.0	μΑ		
Power Off I Current	_eakage	lOFF	V <sub>IN</sub> , V <sub>OUT</sub>	=0~3.6V	0		10.0	μΑ		
Quiescent S	upply	laa	$V_{IN} = V_{CC}$	or GND	2.7~3.6		20.0			
Current		lcc	V <sub>CC</sub> ≤ (V <sub>IN</sub>	, V <sub>OUT</sub> ) ≦ 3.6V	2.7~3.6	_	± 20.0	$\mu$ A		
Increase In Input	ICC Per	∆ارح	V <sub>IH</sub> = V <sub>CC</sub> -	0.6V	2.7~3.6	_	750	μΑ		

### **ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta =  $-40\sim85^{\circ}$ C,  $2.3V \le V_{CC} \le 2.7V$ )

PARA	METER	SYMBOL	TEST	TEST CONDITION		MIN.	MAX.	UNIT																
Input	"H" Level	V <sub>IH</sub>			2.3~2.7	1.6	_	V																
Voltage	"L" Level	V <sub>IL</sub>			2.3~2.7	_	0.7	V																
		.,	I <sub>OH</sub> = -100μA	2.3~2.7	V <sub>CC</sub> - 0.2																			
	"H" Level	VOH	VIH or VIL	$I_{OH} = -4mA$	2.3	2.0	_																	
Output				VIH or VIL	VIH or VIL	VIH or VIL	VIH or VIL	VIH or VIL	VIH or VIL	I <sub>OH</sub> = -6mA	2.3	1.8	_	v										
Voltage												I <sub>OH</sub> = -8mA	2.3	1.7	_	V								
		V	$I_{OL} = 100 \mu A$	I <sub>OL</sub> = 100μA	2.3~2.7	_	0.2																	
	"L" Level	VOL	V <sub>IN</sub> =			VIN - VIH or VIL														I <sub>OL</sub> = 6mA	2.3	_	0.4	
			VIH OF VIL	I <sub>OL</sub> = 8mA	2.3	_	0.6																	
Input Leak	age Current	l <sub>IN</sub>	$V_{IN} = 0 \sim 3.6$	5V	2.3~2.7	_	± 5.0	μΑ																
3-State Out Off-State C		loz	VINI = VILL OF VII		2.3~2.7	_	± 10.0	$\mu$ A																
Power Off Current	Leakage	lOFF	V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6V		0	_	10.0	$\mu$ A																
Quiescent S	Supply	laa	$V_{IN} = V_{CC}$	or GND	2.3~2.7	_	20.0																	
Current		lcc	$V_{CC} \le (V_{IN})$	, V <sub>OUT</sub> )≦3.6V <sub>CC</sub>	2.3~2.7	_	± 20.0	$\mu$ A																

#### **ELECTRICAL CHARACTERISTICS**

DC characteristics (Ta =  $-40\sim85^{\circ}$ C,  $1.8V \le V_{CC} < 2.3V$ )

PARA	METER	SYMBOL	TEST	TEST CONDITION		MIN.	MAX.	UNIT	
Input	"H" Level	V <sub>IH</sub>				0.7 × V <sub>CC</sub>	_	<b>&gt;</b>	
Voltage	"L" Level	$V_{IL}$			1.8~2.3	_	0.2 x V <sub>CC</sub>	V	
Outrot	"H" Level	Voн	V <sub>IN</sub> =	I <sub>OH</sub> = -100μA	1.8	V <sub>C</sub> C - 0.2	_		
Output Voltage			V <sub>IH</sub> or V <sub>IL</sub>	AIH OL AIL	I <sub>OH</sub> = -4mA	1.8	1.4	_	V
Voltage	"L" Level	V	V <sub>IN</sub> =	V <sub>IN</sub> =	I <sub>OL</sub> = 100μA	1.8	_	0.2	
	L Levei	VOL	VIH or VIL	I <sub>OL</sub> = 4mA	1.8	_	0.3		
Input Leak	age Current	ΙΝ	$V_{IN} = 0 \sim 3.6$	SV .	1.8	_	± 5.0	μΑ	
3-State Out Off-State C		loz	V <sub>IN</sub> = V <sub>IH</sub> o V <sub>OUT</sub> = 0~3		1.8	_	± 10.0	$\mu$ A	
Power Off Current	Leakage	I <sub>OFF</sub> V <sub>IN</sub> , V <sub>OUT</sub> = 0~3.6V		0		10.0	μΑ		
Quiescent Supply		lee	$V_{IN} = V_{CC}$	V <sub>IN</sub> = V <sub>CC</sub> or GND		_	20.0	Λ	
Current		lcc	$V_{CC} \leq (V_{IN},$	V <sub>OUT</sub> ) ≤ 3.6V	1.8	_	± 20.0	$\mu$ A	

# AC characteristics (Ta = $-40 \sim 85$ °C, Input t<sub>f</sub> = t<sub>f</sub> = 2.0ns, C<sub>L</sub> = 30pF, R<sub>L</sub> = 500 $\Omega$ )

PARAMETER	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	MIN.	MAX.	UNIT
	<b>+</b>		1.8	1.5	5.7	
Propagation Delay Time	t <sub>pLH</sub>	(Fig.1, 2)	2.5 ± 0.2	1.0	4.3	ns
	t <sub>pHL</sub>		3.3 ± 0.3	0.8	3.4	
3-State Output Enable	t <sub>pZL</sub> t <sub>pZH</sub>		1.8	1.5	7.6	
Time		(Fig.1, 3)	2.5 ± 0.2	1.0	5.7	ns
Time			3.3 ± 0.3	0.8	4.2	
2 State Output Disable	+		1.8	1.5	5.7	
3-State Output Disable Time	t <sub>pLZ</sub>	(Fig.1, 3)	2.5 ± 0.2	1.0	4.8	ns
Time	t <sub>pHZ</sub>		3.3 ± 0.3	0.8	4.1	
	+		1.8	_	0.5	
Output To Output Skew	<sup>t</sup> osLH +	(Note 11)	2.5 ± 0.2	_	0.5	ns
	<sup>t</sup> osHL		3.3 ± 0.3	_	0.5	

For  $C_L = 50 pF$ , add approximately 300ps to the AC maximum specification.

(Note 11) Parameter guaranteed by design.  $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$ 

Dynamic switching ch	haracteristics (Ta = 25°C	, Input $t_r = t_f = 2.0 \text{ ns}$	$C_{I} = 30pF$
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PARAMETER	SYMBOL	TEST CONDITI	ON	V <sub>CC</sub> (V)	TYP.	UNIT
Quiet Quitnut Maximum		V <sub>IH</sub> = 1.8V, V <sub>IL</sub> = 0V	(Note 12)	1.8	0.15	
Quiet Output Maximum  Dynamic VOL	V <sub>OLP</sub>	$V_{IH} = 2.5V, V_{IL} = 0V$	(Note 12)	2.5	0.25	V
Dynamic VOL		V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V	(Note 12)	3.3	0.35	
Quiet Output Minimum		V <sub>IH</sub> = 1.8V, V <sub>IL</sub> = 0V	(Note 12)	1.8	- 0.15	
Dynamic VOI	VOLV	$V_{IH} = 2.5V, V_{IL} = 0V$	(Note 12)	2.5	-0.25	V
Dynamic VOL		$V_{IH} = 3.3V, V_{IL} = 0V$	(Note 12)	3.3	- 0.35	
Quiet Quinut Minimum		V <sub>IH</sub> = 1.8V, V <sub>IL</sub> = 0V	(Note 12)	1.8	1.55	
Quiet Output Minimum Dynamic V <sub>OH</sub>	VOHV	$V_{IH} = 2.5V, V_{IL} = 0V$	(Note 12)	2.5	2.05	V
Dynamic VOH		V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V	(Note 12)	3.3	2.65	

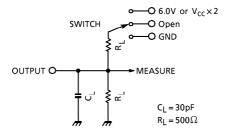
(Note 12) Parameter guaranteed by design.

#### Capacitive characteristics (Ta = 25°C)

PARAMETER	SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	TYP.	UNIT
Input Capacitance	CIN	DIR, OE	1.8, 2.5, 3.3	6	pF
Bus I/O Capacitance	C <sub>1</sub> /O	An, Bn	1.8, 2.5, 3.3	7	pF
Power Dissipation Capacitance	C <sub>PD</sub>	$f_{IN} = 10MHz$ (Note 13)	1.8, 2.5, 3.3	20	pF

(Note 13) CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation :  $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 16 \text{ (per bit)}$ 

Fig.1 Test circuit



PARAMETER	SWITCH		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0V $@V_{CC} = 3.3 \pm 0.3V$ $V_{CC} \times 2 @V_{CC} = 2.5 \pm 0.2V$		
	$V_{CC}x2 @V_{CC} = 2.5 \pm 0.2V$		
	@V <sub>CC</sub> = 1.8V		
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

#### **AC WAVEFORM**

Fig.2 t<sub>pLH</sub>, t<sub>pHL</sub>

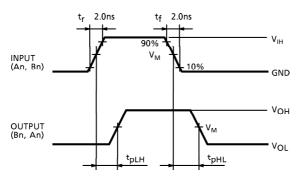
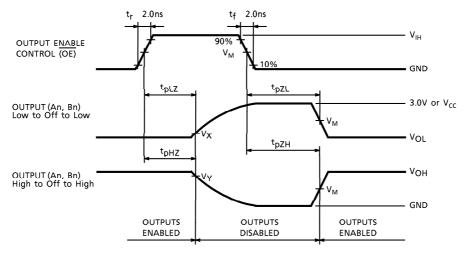


Fig.3  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$ ,  $t_{pZH}$ 

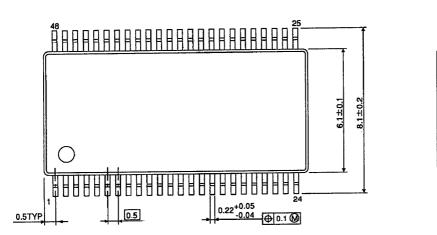


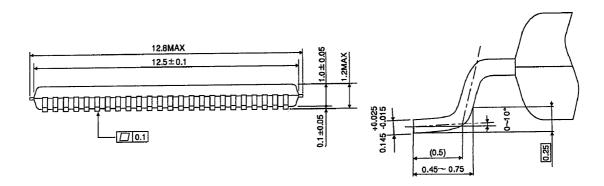
SYMBOL	V <sub>CC</sub>		
STIVIBOL	3.3 ± 0.3V	2.5 ± 0.2V	1.8V
$V_{IH}$	2.7V	V <sub>CC</sub>	V <sub>CC</sub>
$V_{M}$	1.5V	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2
VX	V <sub>OL</sub> + 0.3V	V <sub>OL</sub> + 0.15V	V <sub>OL</sub> + 0.15V
V <sub>Y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V	V <sub>OH</sub> – 0.15V

Unit: mm

#### **OUTLINE DRAWING**

TSSOP48-P-0061-0.50





Weight: 0.25g (Typ.)

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